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SN74AHC1G08

SCLS314O - MARCH 1996-REVISED JUNE 2015

# SN74AHC1G08 Single 2-Input Positive-AND Gate

#### Features 1

- Operating Range 2 V to 5.5 V
- Maximum t<sub>pd</sub> of 7 ns at 5 V
- Low Power Consumption, 10-µA Maximum I<sub>CC</sub>
- ±8-mA Output Drive at 5 V
- Schmitt-Trigger Action at All Inputs Makes the Circuit Tolerant for Slower Input Rise and Fall Time
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds JESD 22
  - 2000-V Human Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)

## 2 Applications

- **Barcode Scanners**
- **Cable Solutions**
- E-Books
- Embedded PCs
- Field Transmitter: Temperature or Pressure Sensors
- **Fingerprint Biometrics**
- HVAC: Heating, Ventilating, and Air Conditioning
- Network-Attached Storage (NAS)
- Server Motherboard and PSU
- Software Defined Radios (SDR)
- TV: High Definition (HDTV), LCD, and Digital
- Video Communications Systems
- Wireless Data Access Cards, Headsets, Keyboards, Mice, and LAN Cards

## 3 Description

The SN74AHC1G08 device is a single 2-input positive-AND gate. The device performs the Boolean function  $Y = A \bullet B$  or Y = A + B in positive logic.

## **Device Information**<sup>(1)</sup>

PART NUMBER	PACKAGE	BODY SIZE (NOM)		
SN74AHC1G08DBV	SOT-23 (5)	2.90 mm × 1.60 mm		
SN74AHC1G08DCK	SC70 (5)	2.00 mm × 1.25 mm		
SN74AHC1G08DRL	SOT (5)	1.60 mm × 1.20 mm		

(1) For all available packages, see the orderable addendum at the end of the data sheet.

## Logic Diagram (Positive Logic)





**ISTRUMENTS** 

Page

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# **Table of Contents**

1	Feat	tures 1
2	Арр	lications 1
3	Des	cription 1
4	Rev	ision History 2
5	Pin	Configuration and Functions
6	Spe	cifications 4
	6.1	Absolute Maximum Ratings 4
	6.2	ESD Ratings 4
	6.3	Recommended Operating Conditions 4
	6.4	Thermal Information 5
	6.5	Electrical Characteristics5
	6.6	Switching Characteristics, $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V} \dots 5$
	6.7	Switching Characteristics, $V_{CC} = 5 V \pm 0.5 V$
	6.8	Operating Characteristics 6
	6.9	Typical Characteristics 6
7	Para	ameter Measurement Information
8	Deta	ailed Description 8
	8.1	Overview 8

	8.2	Functional Block Diagram 8
	8.3	Feature Description
	8.4	Device Functional Modes
9	Appl	ication and Implementation
	9.1	Application Information
	9.2	Typical Application
10	Pow	er Supply Recommendations 10
11	Layo	out
	11.1	Layout Guidelines 10
	11.2	Layout Example 11
12	Devi	ce and Documentation Support 11
	12.1	Documentation Support 11
		Community Resources 11
	12.3	Trademarks 11
	12.4	Electrostatic Discharge Caution 11
	12.5	Glossary 11
13		hanical, Packaging, and Orderable
	Infor	mation 12

## 4 Revision History

2

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

CI	hanges from Revision N (November 2012) to Revision O	Page
•	Removed Ordering Information table.	1
•	Added Applications	1
•	Added Device Information table.	1
•	Added ESD Ratings table	4
•	Added Thermal Information table.	5

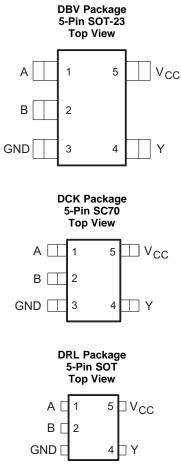
### Changes from Revision M (June 2005) to Revision N

Changed document format from Quicksilver to DocZone	1	i
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### SN74AHC1G08 SCLS314O – MARCH 1996–REVISED JUNE 2015

## 5 Pin Configuration and Functions



See mechanical drawings for dimensions (in *Mechanical, Packaging, and Orderable Information*).

### **Pin Functions**

PIN		I/O	DESCRIPTION				
NO.	NAME	1/0	DESCRIPTION				
1	А	I	Data Input				
2	В	I	Data Input				
3	GND	—	Ground				
4	Y	0	Data Output				
5	VCC	_	Power				

## 6 Specifications

## 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		-0.5	7	V
VI	Input voltage <sup>(2)</sup>	-0.5	7	V	
Vo	Output voltage <sup>(2)</sup>		-0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	Input clamp current	V <sub>I</sub> < 0		-20	mA
I <sub>OK</sub>	Output clamp current	$V_{O}$ < 0 or $V_{O}$ > $V_{CC}$		±20	mA
I <sub>O</sub>	Continuous output current	$V_{O} = 0$ to $V_{CC}$		±25	mA
	Continuous current through $V_{CC}$ or	GND		±50	mA
TJ	Junction temperature			150	°C
T <sub>stg</sub>	Storage temperature		-65	150	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

## 6.2 ESD Ratings

			VALUE	UNIT
	Flootroototio	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins <sup>(1)</sup>	2000	
V <sub>(ESD)</sub>	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101, all pins <sup>(2)</sup>	1000	V

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

## 6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		2	5.5	V
		V <sub>CC</sub> = 2 V	1.5		
VIH	High-level input voltage	$V_{CC} = 3 V$	2.1		V
		V <sub>CC</sub> = 5.5 V	3.85		
		V <sub>CC</sub> = 2 V		5.5	
V <sub>IL</sub>	Low-level Input voltage	$V_{CC} = 3 V$		0.9	V
		$V_{CC} = 5.5 V$		1.65	
VI	Input voltage		0	5.5	V
Vo	Output voltage		0	V <sub>CC</sub>	V
		V <sub>CC</sub> = 2 V		-50	μA
I <sub>OH</sub>	High-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		-4	
		$V_{CC} = 5 V \pm 0.5 V$		-8	mA
		$V_{CC} = 2 V$		50	μA
I <sub>OL</sub>	Low-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		4	
		$V_{CC} = 5 V \pm 0.5 V$		8	mA
A+/A.,	Input transition rise or fell rate	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		100	201
Δt/Δv	Input transition rise or fall rate	$V_{CC} = 5 V \pm 0.5 V$		ns/V	
T <sub>A</sub>	Operating free-air temperature		-55	125	°C

 All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, SCBA004.



## 6.4 Thermal Information

			SN74AHC1G08		
	THERMAL METRIC <sup>(1)</sup>	DBV (SOT-23)	DCK (SC70)	DRL (SOT)	UNIT
		5 PINS	5 PINS	5 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	206	252	142	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

## 6.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	N	T <sub>A</sub> = 25°C			T <sub>A</sub> = −55°C to	UNIT	
PARAMETER	TEST CONDITIONS	V <sub>cc</sub>	MIN	TYP	MAX	MIN	MAX	UNIT
V <sub>OH</sub>		2 V	1.9	2		1.9		
	I <sub>OH</sub> = -50 μA	3 V	2.9	3		2.9		
		4.5 V	4.4	4.5		4.4		V
	$I_{OH} = -4 \text{ mA}$	3 V	2.58			2.48		
	I <sub>OH</sub> = -8 mA	4.5 V	3.94			3.8		
		2 V			0.1		0.1	
	I <sub>OL</sub> = 50 μA	3 V			0.1		0.1	
V <sub>OL</sub>		4.5 V			0.1		0.1	V
	I <sub>OL</sub> = 4 mA	3 V			0.36		0.44	
	I <sub>OL</sub> = 8 mA	4.5 V			0.36		0.44	
l <sub>l</sub>	$V_1 = 5.5 V \text{ or GND}$	0 V to 5.5 V			±0.1		±1	μA
I <sub>CC</sub>	$V_{I} = V_{CC} \text{ or } GND, \qquad I_{O} = 0$	5.5 V			1		10	μA
C <sub>i</sub>	$V_{I} = V_{CC}$ or GND	5 V		4	10		10	pF

## 6.6 Switching Characteristics, $V_{CC}$ = 3.3 V ± 0.3 V

over recommended operating free-air temperature range,  $V_{CC}$  = 3.3 V ± 0.3 V (unless otherwise noted) (see Figure 2)

PARAMETER	FROM	TO	OUTPUT	т	<sub>A</sub> = 25°C		T <sub>A</sub> = −40°C t	o 85°C	T <sub>A</sub> = –55° 125°C	C to	UNIT			
	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX				
t <sub>PLH</sub>	A or D	V			6.2	8.8	1	10.5	1	11				
t <sub>PHL</sub>	A or B	AUD	I	Y C <sub>L</sub> = 15 pF	CL = 15 pF	$O_{L} = 15 \text{ pr}$		6.2	8.8	1	10.5	1	11	ns
t <sub>PLH</sub>	A D	V			8.7	12.3	1	14	1	14.5				
t <sub>PHL</sub>	A or B	ř	C <sub>L</sub> = 50 pF		8.7	12.3	1	14	1	14.5	ns			

## 6.7 Switching Characteristics, $V_{CC} = 5 V \pm 0.5 V$

over recommended operating free-air temperature range,  $V_{CC}$  = 5 V ± 0.5 V (unless otherwise noted) (see Figure 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	OUTPUT CAPACITANCE	Т	<sub>A</sub> = 25°C		T <sub>A</sub> = -40°C	to 85°C	T <sub>A</sub> = -55° 125°(	C to	UNIT					
		(001201)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX						
t <sub>PLH</sub>	A or B	V	0 45 -5		4.3	5.9	1	7	1	7.5	20					
t <sub>PHL</sub>	AUD	Ŷ	Ť	C <sub>L</sub> = 15 pF	$C_L = 15 \text{ pr}$	$G_L = 15 \text{ pF}$	$C_L = 15 \text{ pr}$	CL = 15 pr		4.3	5.9	1	7	1	7.5	ns
t <sub>PLH</sub>	A or D	V	C <sub>L</sub> = 50 pF	0 50 - 5		5.8	7.9	1	9	1	9.5					
t <sub>PHL</sub>	A or B	ř			5.8	7.9	1	9	1	9.5	ns					

### SN74AHC1G08

SCLS314O - MARCH 1996 - REVISED JUNE 2015



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## 6.8 Operating Characteristics

$V_{CC} = 5 V, T_A = 25^{\circ}C$
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	PARAMETER	TEST C	CONDITIONS	TYP	UNIT
C <sub>pd</sub>	Power dissipation capacitance	No load,	f = 1 MHz	18	pF

## 6.9 Typical Characteristics

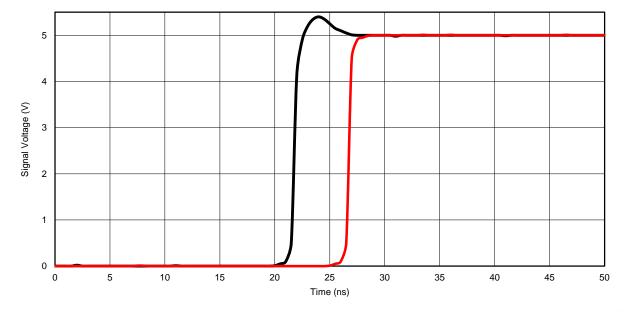
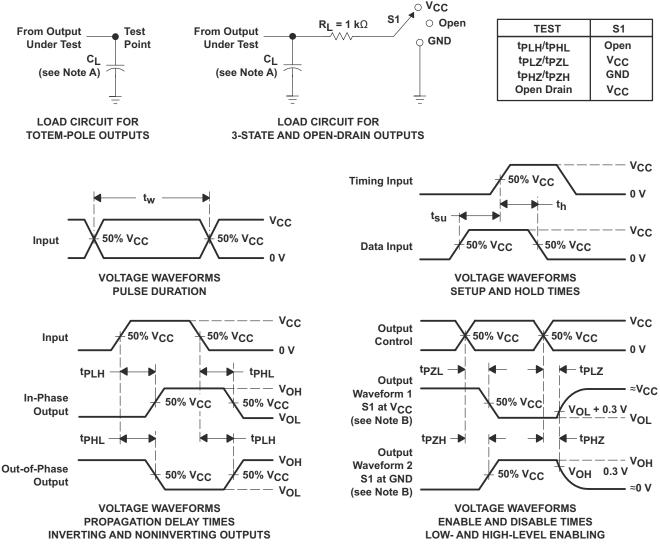


Figure 1. Response Time vs Output Voltage ( $T_A = 25^{\circ}C$ ,  $V_A = 5 V$ )



## 7 Parameter Measurement Information



- A. C<sub>L</sub> includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control.

Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.

- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz, Z<sub>0</sub> = 50  $\Omega$ , t<sub>r</sub>  $\leq$  3 ns, t<sub>f</sub>  $\leq$  3 ns.
- D. The outputs are measured one at a time with one input transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.

Figure 2. Load Circuit and Voltage Waveforms

SN74AHC1G08 SCLS3140 – MARCH 1996–REVISED JUNE 2015

## 8 Detailed Description

## 8.1 Overview

The SN74AHC1G08 device is a single 2-input positive-AND gate. The device performs the Boolean function  $Y = A \bullet B$  or Y = A + B in positive logic.

## 8.2 Functional Block Diagram

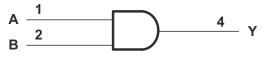


Figure 3. Logic Diagram (Positive Side)

### 8.3 Feature Description

The SN74AHC1G08 device has a wide operating  $V_{CC}$  range of 2 V to 5.5 V, which allows it to be used in a broad range of systems. The low propagation delay allows fast switching and higher speeds of operation. In addition, the low-power consumption makes this device a good choice for portable and battery power-sensitive applications.

## 8.4 Device Functional Modes

Table 1 lists the functional modes for SN74AHC1G08.

### Table 1. Function Table

INP	OUTPUT	
Α	В	Y
Н	Н	Н
L	Х	L
Х	L	L



## 9 Application and Implementation

### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 9.1 Application Information

A common application for AND gates is their use in power sequencing. Power sequencing is often employed in applications that require a processor or other delicate device with specific voltage timing requirements in order to protect the device from malfunctioning. Using the SN74AHC1G08 to verify that the processor has turned on can protect it from any harmful signals.

## 9.2 Typical Application

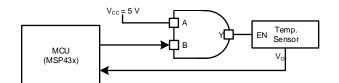


Figure 4. Power Sequencing Application

### 9.2.1 Design Requirements

The SN74AHC1G08 device uses CMOS technology and has balanced output drive. Take care to avoid bus contention because it can drive currents that would exceed maximum limits.

The SN74AHC1G08 allows switching control of analog and digital signals with a digital control signal. All input signals should remain as close to either 0 V or  $V_{CC}$  for optimal operation.

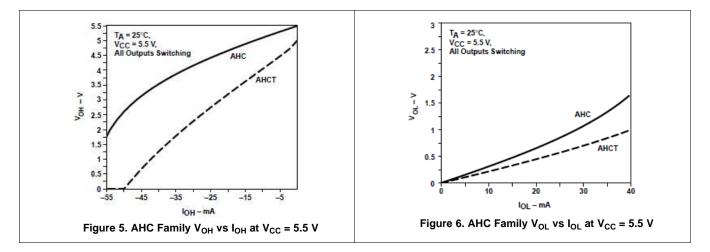
### 9.2.2 Detailed Design Procedure

- 1. Recommended input conditions:
  - For rise time and fall time specifications, see  $\Delta t/\Delta v$  in the *Recommended Operating Conditions* table.
  - For specified high and low levels, see V<sub>IH</sub> and V<sub>IL</sub> in the *Recommended Operating Conditions* table.
  - Inputs and outputs are overvoltage tolerant and can therefore go as high as 5.5 V at any valid V<sub>CC</sub>.
- 2. Recommended output conditions:
  - Load currents should not exceed ±50 mA.
- 3. Frequency selection criterion:
  - The effects of frequency upon the device's power consumption should be studied in CMOS Power Consumption and CPD Calculation, SCAA035.
  - Added trace resistance and capacitance can reduce maximum frequency capability; follow the layout practices listed in the *Layout* section.



## **Typical Application (continued)**

### 9.2.3 Application Curves



## **10** Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating listed in the *Recommended Operating Conditions* table.

Each V<sub>CC</sub> terminal should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, a 0.1- $\mu$ F bypass capacitor is recommended. If multiple pins are labeled V<sub>CC</sub>, then a 0.01- $\mu$ F or 0.022- $\mu$ F capacitor is recommended for each V<sub>CC</sub> because the V<sub>CC</sub> pins are tied together internally. For devices with dual-supply pins operating at different voltages, for example V<sub>CC</sub> and V<sub>DD</sub>, a 0.1- $\mu$ F bypass capacitor is recommended for each supply pin. To reject different frequencies of noise, use multiple bypass capacitors in parallel. Capacitors with values of 0.1  $\mu$ F and 1  $\mu$ F are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

## 11 Layout

## 11.1 Layout Guidelines

Reflections and matching are closely related to the loop antenna theory but are different enough to be discussed separately from the theory. When a PCB trace turns a corner at a 90° angle, a reflection can occur. A reflection occurs primarily because of the change of width of the trace. At the apex of the turn, the trace width increases to 1.414 times the width. This increase upsets the transmission-line characteristics, especially the distributed capacitance and self–inductance of the trace which results in the reflection. Not all PCB traces can be straight and therefore some traces must turn corners. Figure 7 shows progressively better techniques of rounding corners. Only the last example (BEST) maintains constant trace width and minimizes reflections.



## 11.2 Layout Example

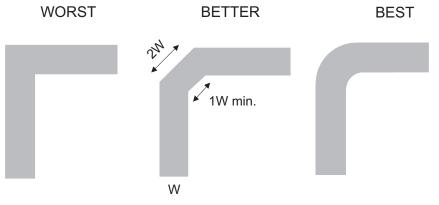


Figure 7. Trace Example

## **12 Device and Documentation Support**

## **12.1** Documentation Support

### 12.1.1 Related Documentation

For related documentation see the following:

- Implications of Slow or Floating CMOS Inputs, SCBA004
- CMOS Power Consumption and CPD Calculation, SCAA035
- Selecting the Right Texas Instruments Signal Switch, SZZA030

## 12.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E<sup>™</sup> Online Community *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support TI's Design Support** Quickly find helpful E2E forums along with design support tools and contact information for technical support.

### 12.3 Trademarks

E2E is a trademark of Texas Instruments. All other trademarks are the property of their respective owners.

## 12.4 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

## 12.5 Glossary

## SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.



## 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser based versions of this data sheet, refer to the left hand navigation.



19-Mar-2015

## **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	•	Pins	•	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
SN74AHC1G08DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	(A082 ~ A083 ~ A08G ~ A08L ~ A08S)	Samples
SN74AHC1G08DBVRE4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	A08G	Samples
SN74AHC1G08DBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	A08G	Samples
SN74AHC1G08DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	(A083 ~ A08G ~ A08L ~ A08S)	Samples
SN74AHC1G08DBVTG4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	A08G	Samples
SN74AHC1G08DCKR	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	(AE3 ~ AEG ~ AEL ~ AES)	Samples
SN74AHC1G08DCKRE4	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	(AE3 ~ AEG ~ AEL ~ AES)	Samples
SN74AHC1G08DCKRG4	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	(AE3 ~ AEG ~ AEL ~ AES)	Samples
SN74AHC1G08DCKT	ACTIVE	SC70	DCK	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	(AE3 ~ AEG ~ AEL ~ AES)	Samples
SN74AHC1G08DCKTE4	ACTIVE	SC70	DCK	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	(AE3 ~ AEG ~ AEL ~ AES)	Samples
SN74AHC1G08DCKTG4	ACTIVE	SC70	DCK	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	(AE3 ~ AEG ~ AEL ~ AES)	Samples
SN74AHC1G08DRLR	ACTIVE	SOT	DRL	5	4000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	(AEB ~ AES)	Samples
SN74AHC1G08DRLRG4	ACTIVE	SOT	DRL	5	4000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	(AEB ~ AES)	Samples
SN74AHC1G08HDBV3	LIFEBUY	SOT-23	DBV	5		TBD	Call TI	Call TI	-55 to 125		
SN74AHC1G08HDCK3	LIFEBUY	SC70	DCK	5		TBD	Call TI	Call TI	-55 to 125		

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.





19-Mar-2015

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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#### OTHER QUALIFIED VERSIONS OF SN74AHC1G08 :

Automotive: SN74AHC1G08-Q1

NOTE: Qualified Version Definitions:

• Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

# PACKAGE MATERIALS INFORMATION

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## TAPE AND REEL INFORMATION





## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Baudaa	Deelvere	Deelvere	Dine	000	Deal	Deal	4.0	DO	1/0	D4	14/	Dind
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AHC1G08DBVR	SOT-23	DBV	5	3000	180.0	9.2	3.17	3.23	1.37	4.0	8.0	Q3
SN74AHC1G08DBVR	SOT-23	DBV	5	3000	178.0	9.2	3.3	3.2	1.55	4.0	8.0	Q3
SN74AHC1G08DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
SN74AHC1G08DBVRG4	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
SN74AHC1G08DBVT	SOT-23	DBV	5	250	178.0	9.2	3.3	3.2	1.55	4.0	8.0	Q3
SN74AHC1G08DBVT	SOT-23	DBV	5	250	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
SN74AHC1G08DBVTG4	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
SN74AHC1G08DCKR	SC70	DCK	5	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
SN74AHC1G08DCKR	SC70	DCK	5	3000	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
SN74AHC1G08DCKT	SC70	DCK	5	250	180.0	9.2	2.3	2.55	1.2	4.0	8.0	Q3
SN74AHC1G08DCKT	SC70	DCK	5	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
SN74AHC1G08DCKT	SC70	DCK	5	250	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
SN74AHC1G08DRLR	SOT	DRL	5	4000	180.0	9.5	1.78	1.78	0.69	4.0	8.0	Q3
SN74AHC1G08DRLR	SOT	DRL	5	4000	180.0	8.4	1.98	1.78	0.69	4.0	8.0	Q3

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# PACKAGE MATERIALS INFORMATION

22-May-2015



*All dimensions are nominal							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AHC1G08DBVR	SOT-23	DBV	5	3000	205.0	200.0	33.0
SN74AHC1G08DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
SN74AHC1G08DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
SN74AHC1G08DBVRG4	SOT-23	DBV	5	3000	180.0	180.0	18.0
SN74AHC1G08DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
SN74AHC1G08DBVT	SOT-23	DBV	5	250	202.0	201.0	28.0
SN74AHC1G08DBVTG4	SOT-23	DBV	5	250	180.0	180.0	18.0
SN74AHC1G08DCKR	SC70	DCK	5	3000	180.0	180.0	18.0
SN74AHC1G08DCKR	SC70	DCK	5	3000	180.0	180.0	18.0
SN74AHC1G08DCKT	SC70	DCK	5	250	205.0	200.0	33.0
SN74AHC1G08DCKT	SC70	DCK	5	250	180.0	180.0	18.0
SN74AHC1G08DCKT	SC70	DCK	5	250	180.0	180.0	18.0
SN74AHC1G08DRLR	SOT	DRL	5	4000	184.0	184.0	19.0
SN74AHC1G08DRLR	SOT	DRL	5	4000	202.0	201.0	28.0

DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



- All linear dimensions are in millimeters. A.
  - This drawing is subject to change without notice. Β.
  - Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side. C.
  - D. Falls within JEDEC MO-178 Variation AA.



DCK (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES: A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
  - D. Falls within JEDEC MO-203 variation AA.



DRL (R-PDSO-N5)

PLASTIC SMALL OUTLINE



NOTES:

All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994. Α. B. This drawing is subject to change without notice.

🖄 Body dimensions do not include mold flash, interlead flash, protrusions, or gate burrs. Mold flash, interlead flash, protrusions, or gate burrs shall not exceed 0,15 per end or side.





DRL (R-PDSO-N5)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.
- E. Maximum stencil thickness 0,127 mm (5 mils). All linear dimensions are in millimeters.
- F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- G. Side aperture dimensions over-print land for acceptable area ratio > 0.66. Customer may reduce side aperture dimensions if stencil manufacturing process allows for sufficient release at smaller opening.



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